

Influence of Functional Groups on Charge Transport in Molecular Junctions

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Using density functional theory (DFT), we analyze the influence of five classes of functional groups, as exemplified by NO_2 , OCH_3 , CH_3 , CCl_3 , and I , on the transport properties of a 1,4-benzenedithiolate (BDT) and 1,4-benzenediamine (BDA) molecular junction with gold electrodes. Our analysis demonstrates how ideas from functional group chemistry may be used to engineer a molecule's transport properties, as was shown experimentally and using a semiempirical model for BDA [Nano Lett. **7**, 502 (2007)]. In particular, we show that the qualitative change in conductance due to a given functional group can be predicted from its known electronic effect (whether it is σ/π donating/withdrawing). However, the influence of functional groups on a molecule's conductance is very weak, as was also found in the BDA experiments. The calculated DFT conductances for the BDA species are five times larger than the experimental values, but good agreement is obtained after correcting for self-interaction and image charge effects.

One of the main advantages of molecular based electronics over present day semiconductor technology is the vast flexibility in design and functionality offered by the myriad of available molecules². In order to fully exploit this flexibility for the synthesis of molecular devices, it is vital to establish simple guiding rules to estimate the effect that a given change in the molecule's composition or conformation has on its electrical properties.

So far, most experimental and theoretical work on single-molecule conduction has focused on understanding the basic properties of individual junctions^{3,4,5,6}. On the other hand, few studies have aimed at describing general trends across molecular species^{7,8,9}.

It is well known that the chemistry of a functional parent or parent molecule may be altered in a consistent manner by the attachment of functional groups¹. Further, the influence of a particular functional group on a parent molecule's chemistry may be predicted qualitatively by considering the electronic effect of the functional group.

We will demonstrate how such ideas may also be applied to describe the influence of a functional group on a parent molecule's transport properties. This was recently shown experimentally for BDA, and the results were explained by scal-

ing the molecule's empirical conductance value by the calculated ionization potentials in the gas phase for the BDA species with two bonded Au atoms¹⁰. By employing these concepts from functional group chemistry, we may engineer the electronic transport properties of a known functional parent. This may be done using a functional group whose frontier orbitals have the same symmetry as the conducting orbital of the parent molecule (σ or π). Groups with donating/withdrawing electronic effects may then be used to raise/lower the eigenenergy of the conducting orbital.

In this paper, we analyze the influence of functional groups on the conductance of both a 1,4-benzenedithiolate ($\text{C}_6\text{H}_4\text{S}_2$ or BDT) and a 1,4-benzenediamine ($\text{C}_6\text{H}_4(\text{NH}_2)_2$ or BDA) molecular junction between gold contacts. We consider these molecules because BDT is perhaps the best studied molecule for charge transport^{3,4,11}, while the influence of functional groups on the BDA molecule has been recently studied experimentally¹⁰. In particular, we shall consider prototypical functional groups from each of the five electronic categories, as shown in Table I. These categories are: (1) withdrawal by conjugation through the π network (π withdrawal), (2) donation by conjugation through the π network (π donation), (3) donation by inductive effect through the σ network (σ donation), (4) withdrawal by inductive effect through the σ network (σ withdrawal), and (5) withdrawal by inductive effect through the σ network with donation by conjugation through the π network (σ withdrawal & π donation)¹. For each electronic effect categorization we have selected as respective examples a nitro group (NO_2), a methoxy group (OCH_3), a methyl group (CH_3), a trichloromethyl group (CCl_3), and an iodo group (I). Other examples of functional groups from each category are also provided in Table I.

All calculations have been performed using the SIESTA density functional theory (DFT) code¹² with the PBE exchange correlation (xc) functional¹³, a double zeta polarized (DZP) basis set, and a mesh cutoff of 200 Ry. We first adsorbed the molecules on a five layer thick gold (111) slab and relaxed the molecule and the three outermost surface layers. The supercell contained 3×3 gold atoms in the surface plane, within which we used 2×2 k -points. A pyramid of four gold atoms attached to the five layers of gold (111) was then introduced in the supercell to simulate the tip of a scanning tun-

TABLE I: Functional group categorization by electronic effect with further examples¹.

Functional Group	Structure	Electronic Effect	Other Examples
NO_2 nitro		π withdrawal	CN, COR, SO_3R
OCH_3 methoxy		π donation	NR_2 , OR
CH_3 methyl		σ donation	C_2H_5 , C_3H_7 alkyls
CCl_3 trichloromethyl		σ withdrawal	CF_3 , NR_3^+
I iodo		σ withdrawal & π donation	F, Cl, Br halogens

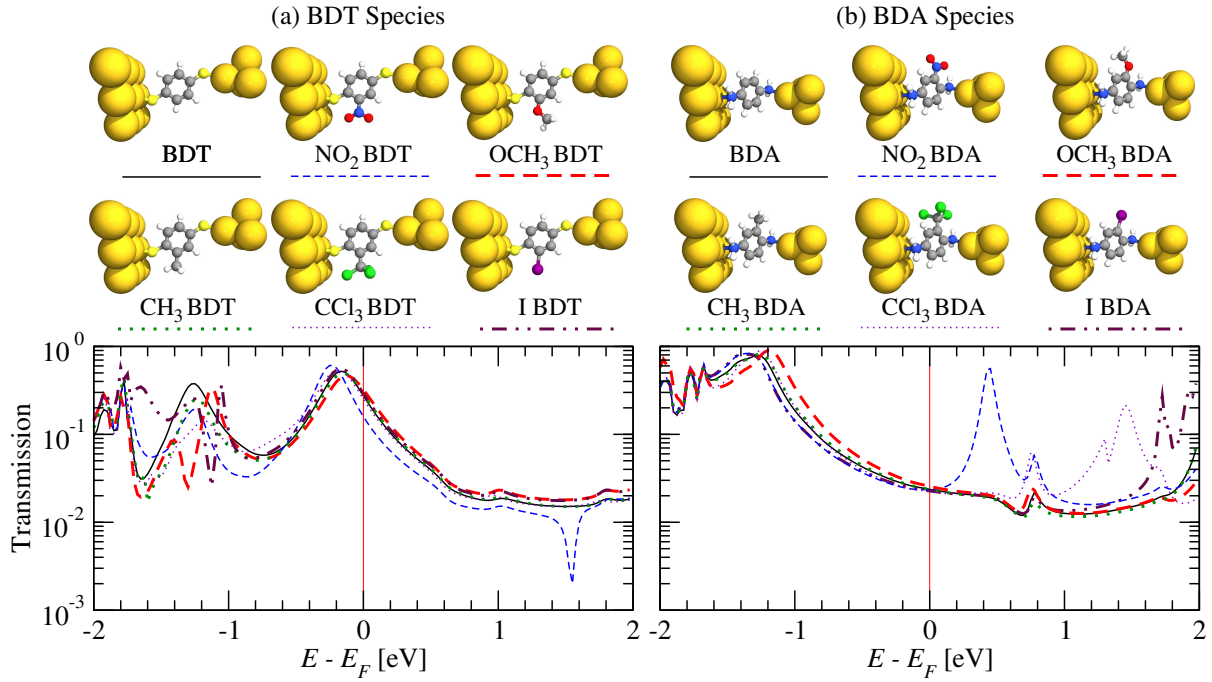


FIG. 1: (Color online). Schematics of (a) BDT species and (b) BDA species bonded between a gold (111) surface and tip, and their transmission functions versus energy $E - E_F$ in eV, relative to the metal's Fermi energy E_F .

neling microscope (STM). The pyramid was placed with its apex atom close to the unbound S/N atom of the molecule, and upon further relaxation the molecule bonds to the gold apex atom, as shown in Fig. 1.

In this way we model a low temperature conductance measurement for a low molecular coverage on a gold (111) surface using an STM tip¹⁴. Such a configuration may not accurately describe the results of break-junction experiments, especially for the weakly bound BDA species¹⁵. However, as shown in Ref. 15, such a binding site yields a similar transmission function to more energetically favorable geometries. Thus, our chosen geometry should allow us to discern more broadly applicable trends in the electronic effects of the functional groups, which are our primary interest.

We find that the BDT species (BDT, NO₂BDT, OCH₃BDT, CH₃BDT, and IBDT) prefer the bridge site of the (111) surface and are rotated by approximately 30° to the surface normal¹⁶, as shown in Fig. 1(a). On the other hand, we find that the BDA species (BDA, NO₂BDA, OCH₃BDA, CH₃BDA, and IBDA) prefer the atop site and lie down at an angle of approximately 50° to the surface normal¹⁵, as shown in Fig. 1(b).

Having chosen the contact geometries, we calculated the elastic transmission functions using the non-equilibrium Green's function (NEGF) formalism. The calculation procedure is equivalent to the one described in Ref. 17, except that the Hamiltonian was represented in the SIESTA atomic orbital basis instead of Wannier functions. We note here that the DZP SIESTA basis set has recently been shown to yield transmission functions in quantitative agreement with plane

TABLE II: Conductance G of BDT and BDA species between a gold (111) surface and tip.

BDT Species	G [$2e^2/h$]	BDA Species	G [$2e^2/h$]
BDT	0.28	BDA	0.024
NO ₂ BDT	0.16	NO ₂ BDA	0.024
OCH ₃ BDT	0.32	OCH ₃ BDA	0.026
CH ₃ BDT	0.29	CH ₃ BDA	0.024
CCl ₃ BDT	0.25	CCl ₃ BDA	0.022
I BDT	0.29	I BDA	0.023

wave codes and maximally localized Wannier functions¹⁸. The transmission function was averaged over four k -points in the surface plane, and three gold (111) layers were added on both sides of the molecule before the system was coupled to the bulk leads to ensure a smooth matching of the effective DFT potential.

The calculated transmission functions are shown in Fig. 1. For both BDT and BDA the change in the transmission function, $T(E)$, near the Fermi level when the functional groups are attached, is strikingly small.

The calculated conductances, $G = G_0 T(E_F)$, where $G_0 = 2e^2/h$, for the BDT and BDA species are shown in Table II. As is often the case for DFT transport calculations on molecular contacts, our results differ substantially from the experimental values of 0.011 G_0 obtained for BDT¹¹, and 0.0064 G_0 for BDA¹⁵. We will address this issue in the last part of the paper. At this point, we observe that functional groups whose valence

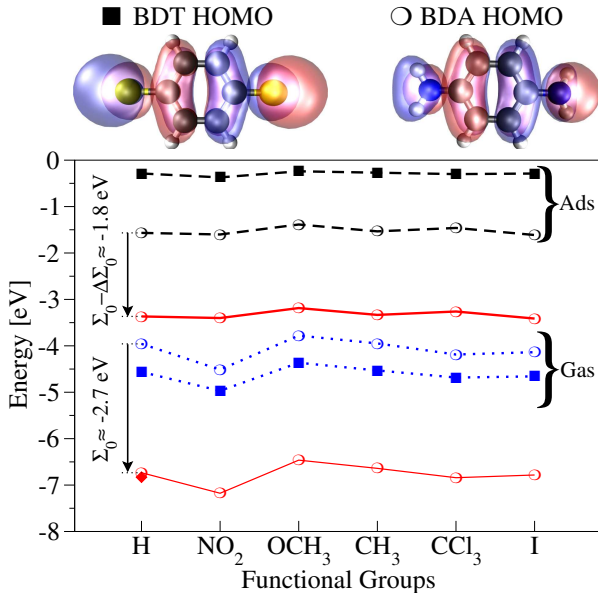


FIG. 2: (Color online). Eigenenergies in eV and isosurfaces of $\pm 0.02 e/\text{\AA}^3$ of HOMOs for BDT species (squares) and BDA species (circles), when adsorbed between a gold (111) surface and tip relative to the metal's Fermi level E_F (black dashed lines), and in the gas phase relative to vacuum (blue dotted lines). For BDA species, the experimental (diamond) and calculated (thin red solid line) gas phase ionization potential I_0 with a SO shift of $\Sigma_0 \approx -2.7$ eV, and the eigenenergies in the junction with a SO shift of $\Sigma_0 + \Delta\Sigma_0 \approx -1.8$ eV (thick red solid line), are shown.

orbitals are of π symmetry seem to have the most influence on the molecule's conductance, with the π withdrawing group lowering the conductance, and the π donating group raising the conductance.

For both BDT and BDA species, we found that transport primarily occurs through the HOMO, which in both cases is a π bonding molecular orbitals, as shown in Fig. 2. In principle, the concept of molecular orbitals is somewhat artificial for a chemisorbed molecule, as hybridization effects will broaden the levels into resonances. One way of generalizing the concept is to consider $\hat{H}_{\text{mol}}$, the projection of the Hamiltonian of the *contacted* system onto the subspace spanned by the basis functions of the molecule. The eigenvectors of $\hat{H}_{\text{mol}}$ can be regarded as molecular orbitals renormalized by the electrodes¹⁷. For molecules which are not too strongly coupled to the electrodes, these renormalized molecular levels are easily identified with the levels of the free molecule.

In Fig. 2 we compare the position of the HOMO level (relative to E_F) of the contacted molecules with the HOMO level (relative to vacuum) of the free gas phase molecules. The variation in the HOMO position with the functional group correlates directly with the variation in the conductance (see Table II) which shows that the current is indeed carried by the HOMO. One exception from this trend is NO_2BDA for which the conductance is not lowered even though the HOMO is significantly down shifted. This is because the LUMO of NO_2BDA lies so low that it also contributes to the charge

transport. From Fig. 2 we can also see that each functional group produces a remarkably consistent shift of the conducting orbital for BDA and BDT. This agrees with the basic premise of functional group chemistry, that a given functional group will alter different parent molecules in a consistent way. We also notice that the two π groups (NO_2 and OCH_3) give the largest shifts of the eigenenergies, while the functional groups with σ symmetry have little influence. Moreover, the π withdrawing functional group (NO_2) delocalizes the HOMO and thereby lowers the eigenenergy, while the π donating functional group (OCH_3) confines the HOMO and thereby increases the eigenenergy. Thus the main ideas of functional group chemistry may be employed to qualitatively predict a functional group's influence on a given functional parent's conducting orbital(s).

We stress that the qualitative effect of the functional groups on the HOMO of the contacted molecule, and thus its conductance, roughly follows from the effect of the functional groups on the free molecule's HOMO, as was found experimentally for BDA¹⁰. This is significant, as it suggests that the latter could be used as a simple descriptor to estimate the impact of a given functional group on the conductance, thereby allowing for an efficient screening of large numbers of functional groups.

When we compare in Fig. 2 the magnitude of the shifts due to the functional groups for both BDT and BDA, we find significantly smaller effects for the contacted molecules than for the gas phase molecules. For example, the shift due to NO_2 on BDT is approximately 0.4 eV in the gas phase, while it is less than 0.1 eV in the contact. This may be understood by recognizing that the gold contacts act as electron sources/sinks for the parent molecule, counteracting the functional group's electronic influence. We thus believe that the weak influence of the functional groups on the conductance is a result of the self-consistent 'pinning' of the HOMO level which ensures the charge neutrality of the molecule. Such effects are indeed physical, but could be artificially enhanced by self-interaction errors in the PBE xc-functional: For partially occupied molecular orbitals, an incomplete cancellation of the Coulomb self interaction by the xc-functional will artificially raise (lower) the energy of that orbital when charge is added (removed) and this will enhance the 'level pinning'.

Self interaction errors also contribute to the well-known underestimation of band gaps by DFT calculations¹⁹. Recently, an atomic self interaction correction (ASIC) scheme^{20,21} has been proposed as a simple cure to this problem for molecular contacts. In general, however, image charges formed in the metallic electrodes when electrons are added to or removed from the molecule also renormalize the molecular levels²², and this effect is not captured by the SIC.

In Table III we compare our DFT calculated conductances for the BDA species with corresponding experimental values¹⁰. The calculated numbers are roughly five times larger than the experimental ones due to the above mentioned deficiencies of the DFT approach. It is, however, interesting to notice that: (i) the weak effect of functional groups is found in both data sets (ii) the qualitative effect of the functional groups on the conductance (increase/decrease) is reproduced by cal-

TABLE III: (Color online). Calculated conductance G_{calc} , SO conductance G_{SO} ¹⁵ with shift $\Sigma_0 - \Delta\Sigma_0 \approx -1.8$ eV, and experimental conductance G_{exp} ¹⁰ for BDA species between a gold (111) surface and tip.

BDA Species	$G_{\text{calc}} [2e^2/h]$	$G_{\text{SO}} [2e^2/h]$	$G_{\text{exp}} [2e^2/h]$
BDA	0.024	0.0035	0.0064 ^a
NO ₂ BDA	0.024	0.0032	—
OCH ₃ BDA	0.026	0.0035	0.0069 ^a
CH ₃ BDA	0.024	0.0034	0.0064 ^a
CCl ₃ BDA	0.022	0.0034	—
Cl BDA	0.015	0.0025	0.0060 ^a
I BDA	0.023	0.0036	—

^aRef. 10

culations. In the second column of Table III we present the results of our conductance calculations after a ‘scissors operator’ (SO), which corrects for self-interaction errors and image charge effects, has been applied to the molecule’s spectrum.

To construct the SO we follow a recent work by Quek *et al.* who applied the scheme to a BDA-gold junction¹⁵. In this method, the underestimation of the DFT HOMO and LUMO are corrected by shifting the occupied/unoccupied orbitals of the contacted molecule by $\Sigma_0^{o,u} = \pm\Sigma_0 = \mp(I_0 + \varepsilon_{\text{HOMO}})$, where $\varepsilon_{\text{HOMO}}$ is the DFT HOMO level for the *free* molecule and I_0 the ionization potential²³. We also calculate the later in DFT from $I_0 = E_{q=+1} - E_{q=0}$, where $E_{q=+1}$ is the total energy of the molecule with charge $+e$ in the gas phase, while $E_{q=0}$ is the total energy in the gas phase of the neutral molecule. For BDA without functional groups we find $I_0 \approx 6.73$ eV, which agrees quantitatively with the experimental value of 6.83 eV¹⁵. We found only small variations in Σ_0 for the different BDA species and have used $\Sigma_0 \approx -2.7$ eV for all molecules, as indicated in Fig. 2.

To estimate the shift of the molecular levels by image charge effects, we first calculate the charge distribution after removing an electron from the free molecule. A Mulliken analysis is then used to approximate this continuous charge distribution by point charges located at the atoms of the molecule. We model the gold contacts as two perfectly conducting surfaces separated by 13.2 Å, which corresponds to the vacuum separation between the opposing gold (111) surfaces. We then obtain an image potential $\Delta\Sigma_0 \approx -0.9$ eV for all of the BDA species considered²⁴. For the BDA molecular junctions, we thus shift all occupied/unoccupied orbitals (obtained by diagonalizing $\hat{H}_{\text{mol}}$) by $\Sigma_0^{o,u} - \Delta\Sigma_0^{o,u} = \pm(\Sigma_0 - \Delta\Sigma_0) \approx \mp 1.8$ eV as indicated in Fig. 2. Calculating the conductance using the renormalized Hamiltonian yields the values shown in Table III. We find that this ‘ad hoc’ correction produces results approximately half those obtained from break-junction experiments on the BDA species¹⁰. This is most probably due to our choice of contact geometry, as our calculated conductance for BDA of 0.024 G_0 is about half the average DFT value calculated over 15 different break-junction contact geometries of 0.046 G_0 ¹⁵. We stress, however, that the use of this SO can only be justified for weakly

coupled molecules with HOMO/LUMO levels well separated from E_F . In Fig. 2 we see this is the case for the BDA species, since the HOMOs are localized near the amine contact groups, providing a poor overlap with the gold contact orbitals. However, for the BDT species, whose HOMOs are rather diffuse around the sulfur atoms, there is a strong overlap with the gold contact orbitals, so that application of the SO is not justified.

In conclusion, we found that the ideas of functional group chemistry may be applied to qualitatively predict the influence of a functional group on the electronic structure of a parent molecule, as has been found for BDA both experimentally and using a semiempirical model¹⁰. However, we also found that functional groups have a very weak influence on a molecule’s conductance in agreement with recent experiments¹⁰. The reason for the weak influence is that charge neutrality pins the HOMO/LUMO molecular levels, making it difficult to shift them relative to E_F . By applying multiple functional groups to the same parent molecule it may be possible to obtain a stronger influence, as was found for BDA¹⁰. By employing a scissors operator correcting for self-interaction errors and image charge effects, we obtained qualitative agreement with experimental conductance values for the BDA species. Our results suggest that effective ‘switching’ of a molecule’s conductance may require a more direct change in the strength or geometry of the molecule’s contacts, to overcome the ‘level pinning’ of the metal.

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APPENDIX A: SCISSORS OPERATOR (SO)

The SO for a free molecule in the gas phase Σ_0 , is given by

$$\Sigma_0 = -(\varepsilon_{\text{HOMO}} + I_0), \quad (\text{A1})$$

where $\varepsilon_{\text{HOMO}}$ is the DFT HOMO level of the free molecule in the gas phase, and I_0 is its first ionization potential, which is defined as

$$I_0 = E_{q=+1} - E_{q=0}. \quad (\text{A2})$$

Here $E_{q=+1}$ is the total gas phase energy calculated for a molecule with charge $q = +e$, while $E_{q=0}$ is the total energy in the gas phase for the neutral molecule.

The occupied/unoccupied orbitals of the contacted molecule are shifted by the same amount $\Sigma_0^{o,u} = \pm\Sigma_0$ for each orbital. This is reasonable for orbitals other than the HOMO and LUMO, since these orbitals are sufficiently far from the Fermi level E_F to have little influence on the contacted molecule’s conductance.

However, this is not the case for the LUMO orbital, especially for NO₂ BDA. In this case, a fully rigorous calculation would shift the DFT LUMO level by $-(\varepsilon_{\text{LUMO}} + E_{ea})$, where $\varepsilon_{\text{LUMO}}$ is the DFT LUMO level for the free molecule and E_{ea} the electron affinity. The later may be calculated similarly to the ionization potential in DFT from $E_{ea} = E_{q=0} - E_{q=-1}$,

where $E_{q=-1}$ is the total energy of the molecule with charge $-e$ in the gas phase. However, as discussed in Ref. 15, when such a shift was calculated for the BDA LUMO, it was found to be approximately equal and opposite to that for the HOMO. For these reasons, we use $\Sigma_0^{o,u} = \pm\Sigma_0$ for all the occupied/unoccupied orbitals.

For a molecule adsorbed near a metal surface, the SO is $\Sigma_0 - \Delta\Sigma_0$, where $\Delta\Sigma_0$ is the charged molecule's image potential arising from the metal surface. To estimate the charge distribution on the molecule $\rho(\mathbf{r})$, we employ the gas phase Mulliken analysis from a charged spin polarized calculation, and use the distribution of unpaired spin up charges. Table IV(a) and IV(b) show the distribution of charges on each atom in (a) 1,4-benzenediamine (BDA) and (b) 3-nitro-1,4-benzenediamine (NO₂BDA) respectively.

The total potential energy gain by moving the charged molecule to the metal surface is

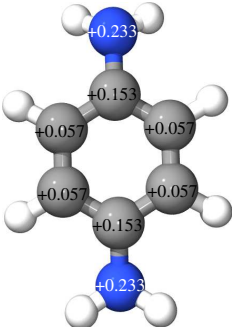
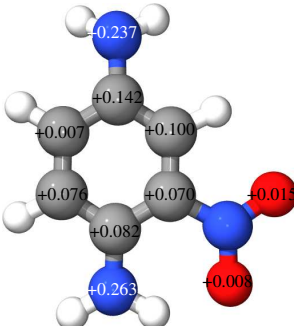
$$\Delta\Sigma_0 = \int d^3\mathbf{r} \rho(\mathbf{r}) \Phi_{\text{ind}}(\mathbf{r}) + \frac{1}{2} \int d^3\mathbf{r} \rho_{\text{ind}}(\mathbf{r}) \Phi_{\text{ind}}(\mathbf{r}), \quad (\text{A3})$$

where the first term is the self energy of the molecule's charge distribution $\rho(\mathbf{r})$ due to the electrostatic potential $\Phi_{\text{ind}}(\mathbf{r})$ induced on the metal surface,

$$\Phi_{\text{ind}}(\mathbf{r}) = \int d^3\mathbf{r}' \frac{\rho_{\text{ind}}(\mathbf{r}')}{\|\mathbf{r} - \mathbf{r}'\|}, \quad (\text{A4})$$

and the second term is the Hartree energy for the charge distribution $\rho_{\text{ind}}(\mathbf{r})$ induced on the metal surface. Approximating our gold surface by a perfect conductor, we find

TABLE IV: Mulliken analysis of charge distribution on (a) BDA and (b) NO₂BDA in the gas phase with total charge $q = +e$.

(a) 1,4-benzenediamine	Q_i [e]	x_i [Å]	y_i [Å]	z_i [Å]
	+0.233	2.508	2.532	4.225
	+0.153	3.435	2.297	5.257
	+0.057	3.770	0.972	5.657
	+0.057	4.027	3.390	5.954
	+0.057	4.766	0.754	6.635
	+0.057	5.028	3.165	6.916
	+0.153	5.438	1.846	7.243
	+0.233	6.553	1.663	8.141
(b) 3-nitro-1,4-benzenediamine	Q_i [e]	x_i [Å]	y_i [Å]	z_i [Å]
	+0.237	2.591	2.540	4.187
	+0.142	3.504	2.302	5.220
	+0.007	4.089	3.397	5.932
	+0.100	3.834	0.989	5.626
	+0.076	5.071	3.177	6.909
	+0.070	4.822	0.773	6.626
	+0.015	4.361	-1.509	6.479
	+0.082	5.506	1.865	7.258
	+0.263	6.601	1.694	8.149
	+0.008	5.979	-0.878	7.847

the induced charge distribution is restricted to the surface, $\rho_{\text{ind}}(\mathbf{r}) = \sigma(\mathbf{r}^\perp)\delta(x)$, where $\sigma(\mathbf{r}^\perp)$ is the induced surface charge distribution, and $\mathbf{r}^\perp = y\mathbf{e}_y + z\mathbf{e}_z$ are the components of $\mathbf{r}$ in the yz -plane, so that

$$\Delta\Sigma_0 = \int d^3\mathbf{r} \rho(\mathbf{r}) \Phi_{\text{ind}}(\mathbf{r}) + \frac{1}{2} \int d^2\mathbf{r}^\perp \sigma(\mathbf{r}^\perp) \Phi_{\text{ind}}(\mathbf{r}^\perp) \Big|_{x=0} \quad (\text{A5})$$

Using the boundary condition that the total electrostatic potential is zero on the metal surface, we find $\Phi_{\text{ind}}(\mathbf{r}^\perp)|_{x=0} = -\Phi_{\text{mol}}(\mathbf{r}^\perp)|_{x=0}$, where $\Phi_{\text{mol}}(\mathbf{r})$ is the Coulomb potential due to the charged molecule. We then find

$$\Delta\Sigma_0 = \int d^3\mathbf{r} \rho(\mathbf{r}) \Phi_{\text{ind}}(\mathbf{r}) - \frac{1}{2} \int d^2\mathbf{r}^\perp \sigma(\mathbf{r}^\perp) \Phi_{\text{mol}}(\mathbf{r}^\perp) \Big|_{x=0} \quad (\text{A6})$$

$$= \int d^3\mathbf{r} \rho(\mathbf{r}) \Phi_{\text{ind}}(\mathbf{r}) - \frac{1}{2} \int d^3\mathbf{r} \rho_{\text{ind}}(\mathbf{r}) \Phi_{\text{mol}}(\mathbf{r}), \quad (\text{A7})$$

$$= \frac{1}{2} \iint d^3\mathbf{r} d^3\mathbf{r}' \frac{\rho(\mathbf{r}) \rho_{\text{ind}}(\mathbf{r}')}{\|\mathbf{r} - \mathbf{r}'\|}. \quad (\text{A8})$$

Since we are modeling the molecule's charge distribution as a series of N point charges at locations $\mathbf{r}_i = \{x_i, y_i, z_i\}$ with charges Q_i , so that

$$\rho(\mathbf{r}) = \sum_{i=1}^N Q_i \delta(\mathbf{r} - \mathbf{r}_i), \quad (\text{A9})$$

and we will only be evaluating the induced potential outside the metal, we may employ the method of image charges, so that

$$\Delta\Sigma_0 = \frac{1}{2} \iint d^3\mathbf{r} d^3\mathbf{r}' \frac{\rho(\mathbf{r}) \rho_{\text{img}}(\mathbf{r}')}{\|\mathbf{r} - \mathbf{r}'\|}, \quad (\text{A10})$$

where we have replaced the induced charge density by the image charge density $\rho_{\text{img}}(\mathbf{r})$ in (A10). We may then write

$$\rho_{\text{img}}(\mathbf{r}) = \sum_{j=1}^N Q_j \rho_{\text{img}}^{(j)}(\mathbf{r}), \quad (\text{A11})$$

so that

$$\Delta\Sigma_0 = \frac{1}{2} \sum_{i,j=1}^N Q_i Q_j \int d^3\mathbf{r} \frac{\rho_{\text{img}}^{(j)}(\mathbf{r})}{\|\mathbf{r}_i - \mathbf{r}\|}, \quad (\text{A12})$$

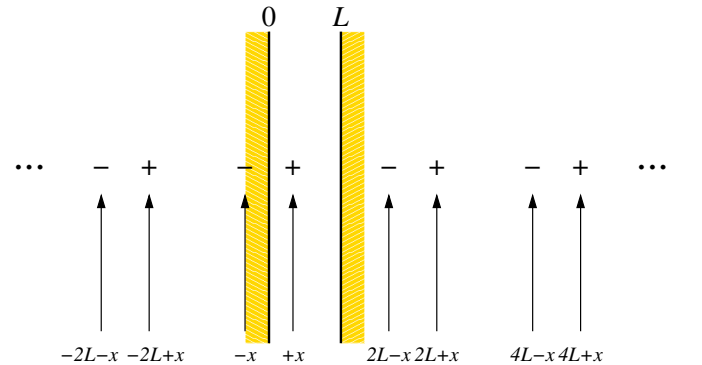


FIG. 3: Locations of image charges for two perfectly conducting surfaces at $x = 0$ and $x = L$ due to a positive charge at $+x$, where $L = 13.2$ Å for our system.

where $\rho_{\text{img}}^{(j)}(\mathbf{r})$ is the image charge density in the metal due to a point charge of 1 e located at $\mathbf{r}_j$.

If the metal our molecule is adsorbed upon consists of a single perfect conducting surface located at $x = 0$, we may model the charge distribution induced in the metal as a series of image charges, so that

$$\rho_{\text{img}}^{(j)}(\mathbf{r}) = -\delta(x + x_j)\delta(\mathbf{r}^\perp - \mathbf{r}_j^\perp), \quad (\text{A13})$$

$$\Delta\Sigma_0 = -\frac{1}{2} \sum_{i,j=1}^N \frac{Q_i Q_j}{\sqrt{(x_i + x_j)^2 + R_{ij}^2}}, \quad (\text{A14})$$

where $R_{ij} = \|\mathbf{r}_i^\perp - \mathbf{r}_j^\perp\|$.

However, if we now introduce a second surface located at $x = L$, an infinite series of image charges is produced, analogous to a series of repeated reflections between two mirrors. We then find

$$\rho_{\text{img}}^{(j)}(\mathbf{r}) = -\delta(\mathbf{r}^\perp - \mathbf{r}_j^\perp) \sum_{n=1}^{\infty} [\delta(x + x_j + 2(n-1)L) + \delta(x + x_j - 2nL) + \delta(x - x_j + 2nL) + \delta(x - x_j - 2nL)], \quad (\text{A15})$$

$$\Delta\Sigma_0 = -\frac{1}{2} \sum_{i,j=1}^N Q_i Q_j \sum_{n=1}^{\infty} \left[\frac{1}{\sqrt{(x_i + x_j - 2nL)^2 + R_{ij}^2}} + \frac{1}{\sqrt{(x_i + x_j + 2(n-1)L)^2 + R_{ij}^2}} \right. \\ \left. - \frac{1}{\sqrt{(x_i - x_j + 2nL)^2 + R_{ij}^2}} - \frac{1}{\sqrt{(x_i - x_j - 2nL)^2 + R_{ij}^2}} \right], \quad (\text{A16})$$

as shown in Fig. 3. We shall take the separation between the opposing gold (111) surfaces of 13.2 Å as our L value. It should be noted that the image charges produced in such a

manner are not physical charges, but are employed as mathematical tools to ensure that the total electrostatic potential is zero on both perfect conducting surfaces.

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²⁴ See Appendix A for further details.